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V41M103C

Vishay General Semiconductor

Dual High Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.40$ V at $I_F = 5$ A

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s, FREE per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V41M103C	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	100	V
Maximum average forward rectified current (fig. 1)	per device	I	40	A
	per diode	I _{F(AV)}	20	
Peak forward surge current 8.3 ms single half sine-wave on rated load per diode	I _{FSM}	250	А	
Operating junction temperature range		T _J ⁽¹⁾	-40 to +175	°C
Storage temperature range		T _{STG}	-55 to +175	

Note

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{0,JA}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 20 A				
V _{RRM}	100 V				
I _{FSM}	250 A				
V _F at I _F = 20 A (125 °C)	0.59 V				
T _J max.	175 °C				
Package	TO-220AB				
Circuit configuration	Common cathode				





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ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _J = 25 °C	V _F ⁽¹⁾	0.49	-	V	
	I _F = 10 A			0.56	-		
	I _F = 20 A			0.67	0.73		
	I _F = 5 A	T _J = 125 °C		0.40	-		
	I _F = 10 A			0.49	-		
	I _F = 20 A			0.59	0.65		
Reverse current at rated V _R per diode	V _B = 70 V	T _J = 25 °C	I _R (2)	0.005	-	mA	
	v _R = 70 v	T _J = 125 °C		3.2	-		
	V _R = 100 V	T _J = 25 °C		-	0.4		
		T _J = 125 °C		8.0	45		
Typical junction capacitance	4 V, 1MHz	-	CJ	2500	-	pF	

Notes

 $^{(2)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽³⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V41M103C	UNIT	
Typical thermal resistance per device	R _{0JC} ⁽¹⁾	1.0	°C/W	

Note

⁽⁴⁾ Thermal resistance junction-to-case to follow JEDEC[®] 51-14 transient dual interface test method (TDIM)

OERDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V41M103C-M3/P	1.88	Р	50/tube	Tube		



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

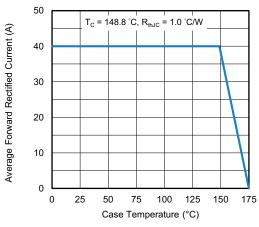


Fig. 1 - Forward Current Derating Curve

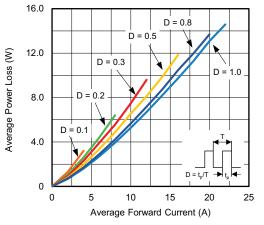


Fig. 2 - Forward Power Loss Characteristics Per Diode

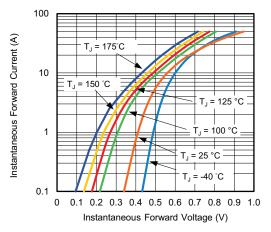


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

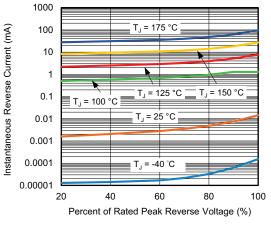
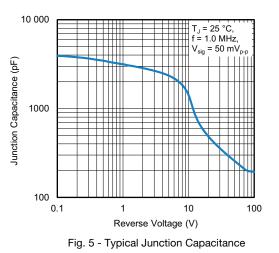
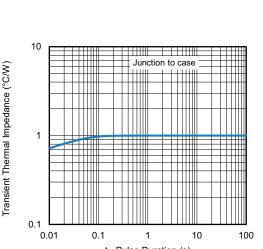


Fig. 4 - Typical Reverse Characteristics Per Diode





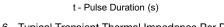


Fig. 6 - Typical Transient Thermal Impedance Per Device

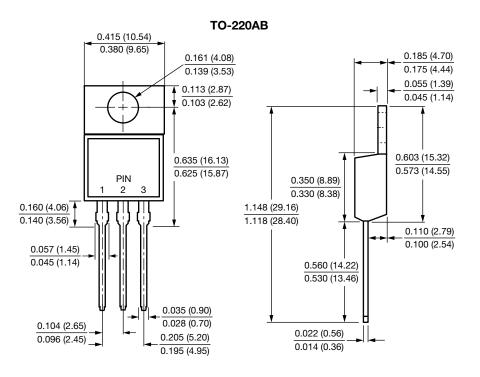
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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